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(71) Applicant (for all designated States except US): **MAT-
SUSHITA ELECTRIC WORKS, LTD.** [JP/JP]; 1048,
Oaza-Kadoma, Kadoma-shi, Osaka 571-8686 (JP).

(72) Inventors; and

(75) Inventors/Applicants (for US only): **AIZAWA, Koichi**

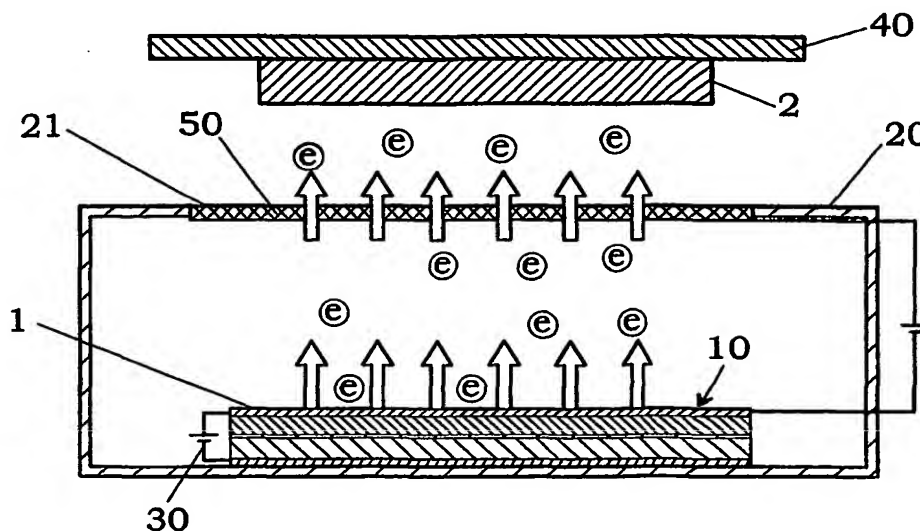
[JP/JP]; c/o Matsushita Electric Works, Ltd., 1048,
Oaza-Kadoma, Kadoma-shi, Osaka 571-8686 (JP). **ICHI-
HARA, Tsutomu** [JP/JP]; c/o Matsushita Electric Works,
Ltd., 1048, Oaza-Kadoma, Kadoma-shi, Osaka 571-8686
(JP). **KOMODA, Takuya** [JP/JP]; c/o Matsushita Electric
Works, Ltd., 1048, Oaza-Kadoma, Kadoma-shi, Osaka
571-8686 (JP). **IKEDA, Jyunji** [JP/JP]; c/o Matsushita
Electric Works, Ltd., 1048, Oaza-Kadoma, Kadoma-shi,
Osaka 571-8686 (JP). **BABA, Toru** [JP/JP]; c/o Matsushita
Electric Works, Ltd., 1048, Oaza-Kadoma, Kadoma-shi,
Osaka 571-8686 (JP).

(74) Agents: **NISHIKAWA, Yoshikiyo** et al.; Hokuto Patent
Attorneys Office, Umeda-Daiichiseimei Bldg. 5th Floor,
12-17, Umeda 1-chome, Kita-ku, Osaka-shi, Osaka 530-
0001 (JP).

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(54) Title: **METHOD AND APPARATUS FOR MODIFYING OBJECT WITH ELECTRONS GENERATED FROM COLD CATHODE ELECTRON EMITTER**



(57) Abstract: Apparatus and method for modifying an object with electrons are provided, by which the object can be uniformly and efficiently modified with the electrons under a pressure substantially equal to atmospheric pressure even when having a relatively wide surface area to be treated. This method uses a cold-cathode electron emitter having the capability of emitting electrons from a planar electron emitting portion according to tunnel effect, and preferably comprising a pair of electrodes, and a strong field drift layer including nanocrystalline silicon disposed between the electrodes. The object is exposed to electrons emitted from the planar electron emitting portion by applying a voltage between the electrodes. It is preferred that an energy of the emitted electrons is selected from a range of 1 eV to 50 keV, and preferably 1 eV to 100 eV.



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